



INTERNATIONAL
GEMOLOGICAL
INSTITUTE

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LABORATORY GROWN DIAMOND REPORT

June 3, 2026

IGI Report Number

LG807644519

Description

LABORATORY GROWN DIAMOND

Shape and Cutting Style

OVAL BRILLIANT

Measurements

9.03 X 6.47 X 3.93 MM

GRADING RESULTS

Carat Weight

1.44 CARAT

Color Grade

D

Clarity Grade

VVS 2

ADDITIONAL GRADING INFORMATION

Polish

EXCELLENT

Symmetry

EXCELLENT

Fluorescence

NONE

Inscription(s)

 LG807644519

Comments: As Grown - No indication of post-growth treatment.
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process. Type II

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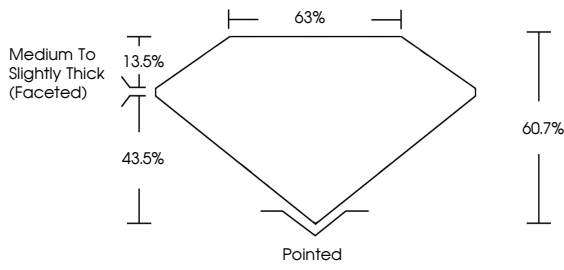
NONE

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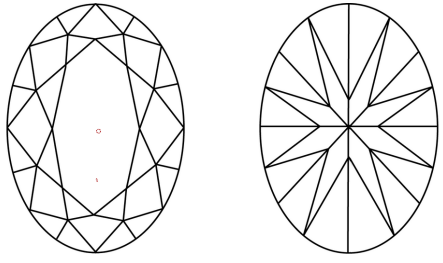
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PROPORTIONS



CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.

COLOR

D E F G H I J Faint Very Light Light

CLARITY

FL IF VVS¹⁻² VS¹⁻² SI¹⁻² I¹⁻³

Flawless Internally Flawless Very Very Slightly Included Very Slightly Included Slightly Included Included



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OVAL BRILLIANT

9.03 X 6.47 X 3.93 MM

Carat Weight

1.44 CARAT

Color Grade

D

Clarity Grade

VVS 2

Depth

43.5%

Table

63%

Girdle

Medium to Slightly Thick (Faceted)

Culet

Pointed

Polish

EXCELLENT

Symmetry

EXCELLENT

Fluorescence

NONE

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